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<u>Atmel</u> AT28C17-15PC

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Features

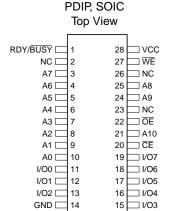
- Fast Read Access Time 150 ns
- Fast Byte Write 200 µs or 1 ms
- Self-Timed Byte Write Cycle
 - Internal Address and Data Latches
 - Internal Control Timer
 - Automatic Clear Before Write
- Direct Microprocessor Control
 - DATA POLLING
 - READY/BUSY Open Drain Output
- Low Power
 - 30 mA Active Current
 - 100 µa CMOS Standby Current
- High Reliability
 - Endurance: 10⁴ or 10⁵ Cycles
 - Data Retention: 10 Years
- 5V \pm 10% Supply
- CMOS & TTL Compatible Inputs and Outputs
- JEDEC Approved Byte Wide Pinout
- Commercial and Industrial Temperature Ranges

Description

The AT28C17 is a low-power, high-performance Electrically Erasable and Program-mable Read Only Memory with easy to use features. The AT28C17 is a 16K memory organized as 2,048 words by 8 bits. The device is manufactured with Atmel's reliable nonvolatile CMOS technology. (continued)

Pin Configurations

Pin Name	Function
A0 - A10	Addresses
CE	Chip Enable
ŌĒ	Output Enable
WE	Write Enable
I/O0 - I/O7	Data Inputs/Outputs
RDY/BUSY	Ready/Busy Output
NC	No Connect
DC	Don't Connect



PLCC Top View 8 29 □ A8 A5 □ 28 □ NC A4 🗆 26 🗆 NC А3 Г A2 □ D OE 24 🗆 A10 CE A0 □ NC [12 22 | 1/07 34 5 9 7 8 6 6 7 1 1 1/06 I/O0 [||01| ||02| ||02| ||03| ||04|

PLCC package pins 1 and 17 are DON'T CONNECT.

AMEL

16K (2K x 8) Parallel EEPROMs

AT28C17

Rev. 0541B-10/98



Note:



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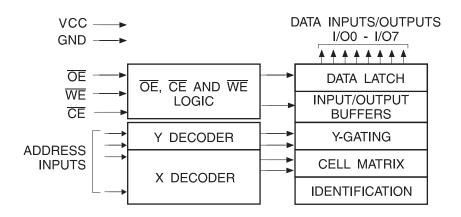


The AT28C17 is accessed like a static RAM for the read or write cycles without the need of external components. During a byte write, the address and data are latched internally, freeing the microprocessor address and data bus for other operations. Following the initiation of a write cycle, the device will go to a busy state and automatically clear and write the latched data using an internal control timer. The device includes two methods for detecting the end of a write cycle, level detection of RDY/BUSY and DATA POLLING of I/O₇. Once the end of a write cycle has been detected, a new access for a read or a write can begin.

The CMOS technology offers fast access times of 150 ns at low power dissipation. When the chip is deselected the standby current is less than 100 μ A.

Atmel's 28C17 has additional features to ensure high quality and manufacturability. The device utilizes error correction internally for extended endurance and for improved data retention characteristics. An extra 32 bytes of EEPROM are available for device identification or tracking.

Block Diagram



Absolute Maximum Ratings*

Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
All Input Voltages (including NC Pins) with Respect to Ground0.6V to +6.25V
All Output Voltages with Respect to Ground0.6V to V _{CC} + 0.6V
Voltage on $\overline{\text{OE}}$ and A9 with Respect to Ground0.6V to +13.5V

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability



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AT28C17

Device Operation

READ: The AT28C17 is accessed like a Static RAM. When $\overline{\text{CE}}$ and $\overline{\text{OE}}$ are low and $\overline{\text{WE}}$ is high, the data stored at the memory location determined by the address pins is asserted on the outputs. The outputs are put in a high impedance state whenever $\overline{\text{CE}}$ or $\overline{\text{OE}}$ is high. This dual line control gives designers increased flexibility in preventing bus contention.

BYTE WRITE: Writing data into the AT28C17 is similar to writing into a Static RAM. A low pulse on the $\overline{\text{WE}}$ or $\overline{\text{CE}}$ input with $\overline{\text{OE}}$ high and $\overline{\text{CE}}$ or $\overline{\text{WE}}$ low (respectively) initiates a byte write. The address location is latched on the last falling edge of $\overline{\text{WE}}$ (or $\overline{\text{CE}}$); the new data is latched on the first rising edge. Internally, the device performs a self-clear before write. Once a byte write has been started, it will automatically time itself to completion. Once a programming operation has been initiated and for the duration of t_{WC} , a read operation will effectively be a polling operation.

FAST BYTE WRITE: The AT28C17E offers a byte write time of 200 μ s maximum. This feature allows the entire device to be rewritten in 0.4 seconds.

READY/BUSY: Pin 1 is an open drain READY/BUSY output that can be used to detect the end of a write cycle. RDY/BUSY is actively pulled low during the write cycle and is released at the completion of the write. The open drain

connection allows for OR-tying of several devices to the same RDY/BUSY line.

DATA POLLING: The AT28C17 provides DATA POLLING to signal the completion of a write cycle. During a write cycle, an attempted read of the data being written results in the complement of that data for I/O₇ (the other outputs are indeterminate). When the write cycle is finished, true data appears on all outputs.

WRITE PROTECTION: Inadvertent writes to the device are protected against in the following ways: (a) V_{CC} sense—if V_{CC} is below 3.8V (typical) the write function is inhibited; (b) V_{CC} power on delay once V_{CC} has reached 3.8V the device will automatically time out 5 ms (typical) before allowing a byte write; and (c) write inhibit—holding any one of \overline{OE} low, \overline{CE} high or \overline{WE} high inhibits byte write cycles.

CHIP CLEAR: The contents of the entire memory of the AT28C17 may be set to the high state by the CHIP CLEAR operation. By setting $\overline{\text{CE}}$ low and $\overline{\text{OE}}$ to 12 volts, the chip is cleared when a 10 msec low pulse is applied to $\overline{\text{WE}}$.

DEVICE IDENTIFICATION: An extra 32 bytes of EEPROM memory are available to the user for device identification. By raising A9 to $12\pm0.5V$ and using address locations 7E0H to 7FFH the additional bytes may be written to or read from in the same manner as the regular memory array.





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DC and AC Operating Range

		AT28C17-15
Operating Temperature (Case)	Com.	0°C - 70°C
	Ind.	-40°C - 85°C
V _{CC} Power Supply		5V ± 10%

Operating Modes

Mode	CE	ŌĒ	WE	I/O
Read	V _{IL}	V _{IL}	V _{IH}	D _{OUT}
Write ⁽²⁾	V _{IL}	V _{IH}	V _{IL}	D _{IN}
Standby/Write Inhibit	V _{IH}	X ⁽¹⁾	X	High Z
Write Inhibit	Х	Х	V _{IH}	
Write Inhibit	Х	V _{IL}	Х	
Output Disable	Х	V _{IH}	Х	High Z
Chip Erase	V _{IL}	V _H ⁽³⁾	V _{IL}	High Z

- Notes: 1. X can be V_{IL} or V_{IH} .
 - 2. Refer to AC Programming Waveforms.
 - 3. $V_H = 12.0V \pm 0.5V$.

DC Characteristics

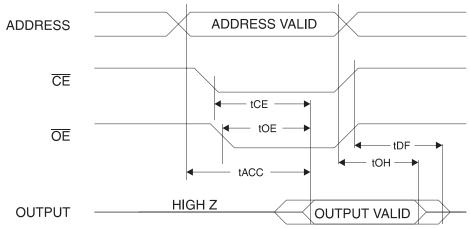
Symbol	Parameter	Condition	Condition		Max	Units
I _{LI}	Input Load Current	$V_{IN} = 0V \text{ to } V_{CC} + 1V$			10	μΑ
I _{LO}	Output Leakage Current	$V_{I/O} = 0V \text{ to } V_{CC}$			10	μΑ
I _{SB1}	V _{CC} Standby Current CMOS	$\overline{\text{CE}} = \text{V}_{\text{CC}} - 0.3 \text{V to V}_{\text{CC}} + 1.0$)V		100	μА
	V Ctondley Cymant III	OF 2.0\(\ta\) .4.0\(\)	Com.		2	mA
I _{SB2}	V _{CC} Standby Current TTL	$\overline{\text{CE}}$ = 2.0V to V _{CC} + 1.0V	Ind.		3	mA
	V Active Comment AC	f = 5 MHz; I _{OUT} = 0 mA	Com.		30	mA
I _{CC}	V _{CC} Active Current AC	CE = V _{IL}	Ind.		45	mA
V _{IL}	Input Low Voltage				0.8	V
V _{IH}	Input High Voltage			2.0		V
V _{OL}	Output Low Voltage	$I_{OL} = 2.1 \text{ mA}$ = 4.0 for RDY/ $\overline{\text{BUSY}}$.4	V
V _{OH}	Output High Voltage	I _{OH} = -400 μA		2.4		V

AT28C17

AC Read Characteristics

		AT280		
Symbol	Parameter	Min	Max	Units
t _{ACC}	Address to Output Delay		150	ns
t _{CE} ⁽¹⁾	CE to Output Delay		150	ns
t _{OE} ⁽²⁾	OE to Output Delay	10	70	ns
t _{DF} ⁽³⁾⁽⁴⁾	CE or OE High to Output Float	0	50	ns
t _{OH}	Output Hold from OE, CE or Address, whichever occurred first	0		ns

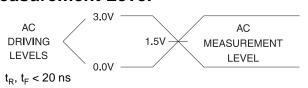
AC Read Waveforms⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾



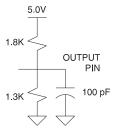
Notes: 1. $\overline{\text{CE}}$ may be delayed up to t_{ACC} - t_{CE} after the address transition without impact on t_{ACC} .

- 2. $\overline{\text{OE}}$ may be delayed up to t_{CE} t_{OE} after the falling edge of $\overline{\text{CE}}$ without impact on t_{CE} or by t_{ACC} t_{OE} after an address change without impact on t_{ACC} .
- 3. t_{DF} is specified from \overline{OE} or \overline{CE} whichever occurs first ($C_L = 5 \text{ pF}$).
- 4. This parameter is characterized and is not 100% tested.

Input Test Waveforms and Measurement Level



Output Test Load



Pin Capacitance

 $f = 1 \text{ MHz}, T = 25^{\circ}C^{(1)}$

Symbol	Тур	Max	Max Units	
C _{IN}	4	6	pF	$V_{IN} = 0V$
C _{OUT}	8	12	pF	V _{OUT} = 0V

Note: 1. This parameter is characterized and is not 100% tested.





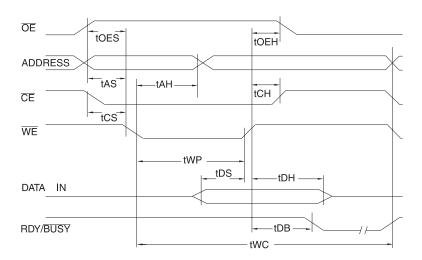


AC Write Characteristics

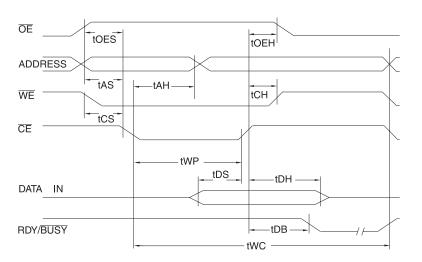
Symbol	Parameter	Min	Тур	Max	Units	
t_{AS}, t_{OES}	Address, OE Set-up Time		10			ns
t _{AH}	Address Hold Time		50			ns
t _{WP}	Write Pulse Width (WE or CE)		100		1000	ns
t _{DS}	Data Set-up Time		50			ns
t _{DH} , t _{OEH}	Data, OE Hold Time		10			ns
t _{CS} , t _{CH}	CE to WE and WE to CE Set-up and Hold Time		0			ns
t _{DB}	Time to Device Busy				50	ns
	Maita Cuala Tima	AT28C17		0.5	1.0	ms
t _{WC}	Write Cycle Time	AT28C17E		100	200	μs

AC Write Waveforms

WE Controlled



CE Controlled



AT28C17



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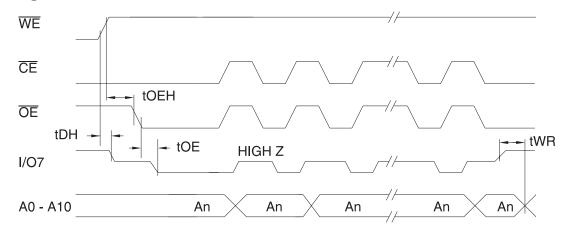
Data Polling Characteristics⁽¹⁾

Symbol	Parameter	Min	Тур	Max	Units
t _{DH}	Data Hold Time	10			ns
t _{OEH}	OE Hold Time	10			ns
t _{OE}	OE to Output Delay ⁽²⁾				ns
t _{WR}	Write Recovery Time	0			ns

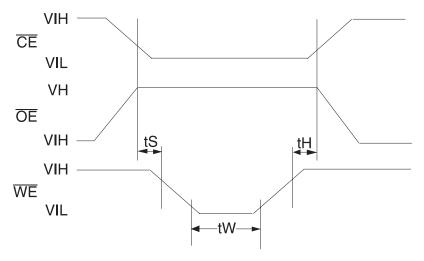
Notes: 1. These parameters are characterized and not 100% tested.

2. See AC Read Characteristics.

Data Polling Waveforms



Chip Erase Waveforms



$$\begin{split} t_S &= t_H = 1 \text{ } \mu \text{sec (min.)} \\ t_W &= 10 \text{ } \text{msec (min.)} \\ V_H &= 12.0 \pm 0.5 V \end{split}$$



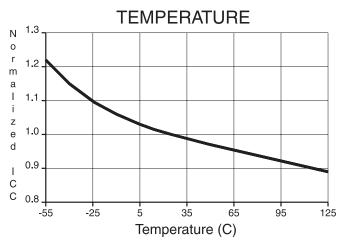


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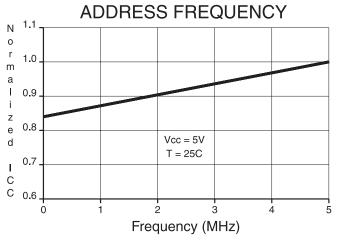


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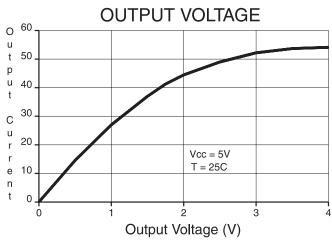
NORMALIZED SUPPLY CURRENT vs.



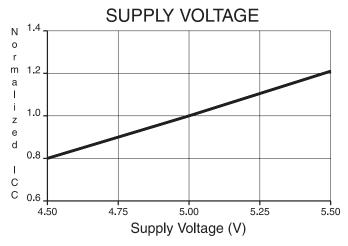
NORMALIZED SUPPLY CURRENT vs.



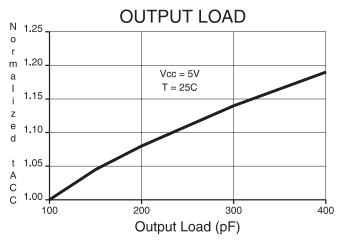
OUTPUT SINK CURRENT vs.



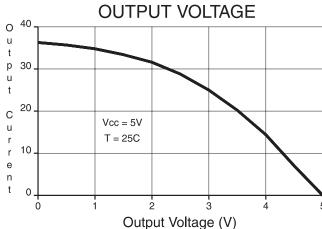
NORMALIZED SUPPLY CURRENT vs.



NORMALIZED ACCESS TIME vs.



OUTPUT SOURCE CURRENT vs.





AT28C17

Ordering Information⁽¹⁾

t _{ACC}	I _{CC} (mA)				
(ns)	Active	Standby	Ordering Code	Package	Operation Range
150	30	0.1	AT28C17(E)-15JC	32J	Commercial
			AT28C17(E)-15PC	28P6	(0°C to 70°C)
			AT28C17(E)-15SC	28S	
	45	0.1	AT28C17(E)-15JI	32J	Industrial
			AT28C17(E)-15PI	28P6	(-40°C to 85°C)
			AT28C17(E)-15SI	28S	

- 1. See Valid Part Numbers table below.
- 2. The 28C17 200 ns and 250 ns speed selections have been removed from valid selections table and are replaced by the faster 150 ns T_{AA} offering.
- 3. The 28C17 ceramic and LCC package offerings have been removed. New designs should utilize the 28C256 ceramic offerings.

Valid Part Numbers

The following table lists standard Atmel products that can be ordered.

Device Numbers	Speed	Package and Temperature Combinations	
AT28C17	15	JC, JI, PC, PI, SC, SI	
AT28C17E	15	JC, JI, PC, PI, SC, SI	
AT28C17	-	W	

Die Products

Reference Section: Parallel EEPROM Die Products

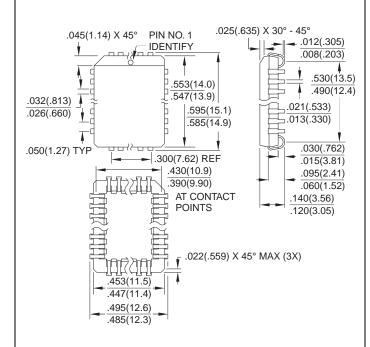
	Package Type			
32J	32-Lead, Plastic J-Leaded Chip Carrier (PLCC)			
28P6	28-Lead, 0.600" Wide, Plastic Dull Inline Package (PDIP)			
28\$	28-Lead, 0.300" Wide, Plastic Gull Wing, Small Outline (SOIC)			
w	Die			
	Options			
Blank	Standard Device: Endurance = 10K Write Cycles; Write Time = 1 ms			
E	High Endurance Option: Endurance = 100K Write Cycles; Write Time = 200 μs			





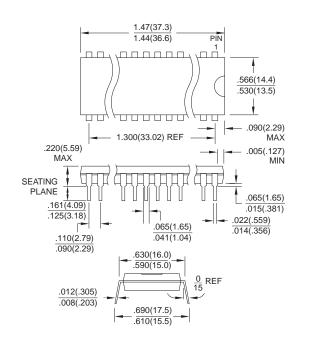
Packaging Information

32J, 32-Lead, Plastic J-Leaded Chip Carrier (PLCC) Dimensions in Inches and (Millimeters)
JEDEC STANDARD MS-018 AA



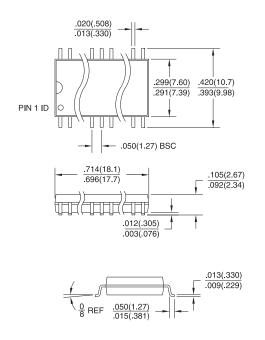
28P6, 28-Lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)

Dimensions in Inches and (Millimeters) JEDEC STANDARD MS-011 AB



28S, 24-Lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)

Dimensions in Inches and (Millimeters)



AT28C17



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